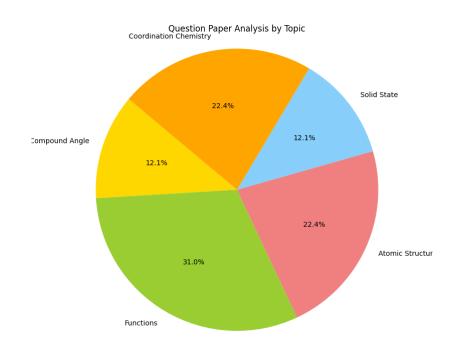
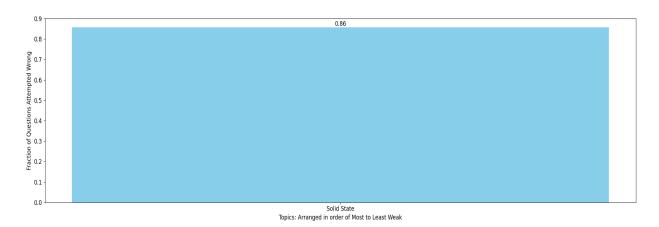
Stargazer_ Total MLAssist - Personalised DPP

Question Paper Analysis:



Weak Topic Analysis:



Practice Questions:

Solid State:

Which of the following defects is also known as dislocation defect?

47.

form of Fe(III)?

	(A) Frenkel defect	(B) Schottky defect			
	(C) Non-stoichiometric defect	(D) Simple interstitial defect			
	PROBLEMS BASED ON ELECTRICAL PROPERTIES				
11.	An element crystallizes in a face-centred cubic (fcc) unit cell with cell edge a. The distance between the centres of two nearest octahedral voids in the crystal lattice is: [Jee Main, 2020]				
	(A) $\frac{a}{\sqrt{2}}$ (B) $\frac{a}{2}$	(C) a	(D) $\sqrt{2}a$		
18.	Match the crystal system / unit cells mentioned in Column I with their characteristic features mentioned in Column II. Indicate your answer by darkening the appropriate bubbles of the 4 ×				
	4 matrix given in the ORS.			[JEE 2007]	
	Column I	Column II			
	(A) simple cubic and face-centred cubic	(P) have these cell parameters a = b = c and			
	$\alpha = \beta = \gamma$				
	(B) cubic and rhombohedral	(Q) are two crystal systems			
	(C) cubic and tetragonal	(R) have only two crystallographic angles of 90° (S) belong to same crystal system.			
	(D) hexagonal and monoclinic				
29.	The composition of a sample of wustite is Fe0.93O1.0. What percentage of iron is present in the				

- 10. Which statements is correct about HCP and CCP lattice
 - (A) Number of tetrahedral voids are twice of octahedral holes
 - (B) 2 tetrahedral and 1 octahedral voids are present in HCP unit cell per atom.
 - (C) Tetrahedral voids = 2 × octahedral voids, is valid for ccp and hcp.
 - (D) Distance between two hexagonal planes in CCP or HCP arrangement is same for a metal exist in both forms.